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High Voltage Protection T/R Switch

Features

- ▶ Up to ±100V input voltage protection
- Low on resistance 15 Ω typical
- Fast switching speed
- ► Effectively, a simple two terminal device
- No external supplies needed

Applications

- Medical ultrasound imaging
- NDT applications
- Fast resettable fuses
- High side switches
- Data acquisition

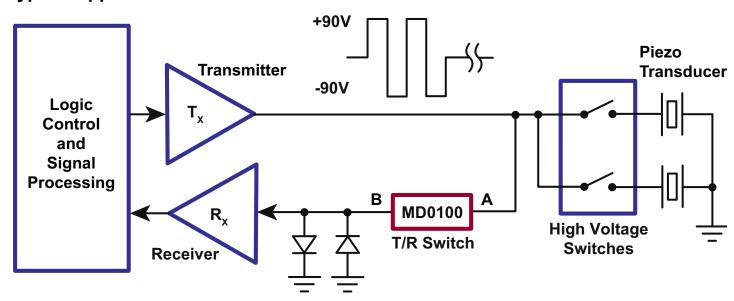
General Description

The Supertex MD0100 is a high voltage, two terminal, bidirectional, current-limiting protection device. The two terminals are interchangeable. It is designed to protect a low noise receiver from the high voltage transmit pulses in ultrasound applications and is commonly referred to as a T/R (transmit and receive) switch.

The MD0100 can be considered as a normally closed switch with a typical switching resistance of 15Ω that allows small signals to pass. Once the voltage drop across the two terminals exceeds a nominal value of $\pm 2.0 \text{V}$, the device will start to turn off. In the off state, the MD0100 can withstand up to $\pm 100 \text{V}$ across its terminals. A small amount of current, typical of $200 \mu A$, is allowed to flow through.

The applications for the MD0100 are not limited to just ultrasound. It can also be used for resettable fuses to protect power lines, output short circuit protection, and data acquisition. The MD0100 is available in the SOT-89 package as a single channel device for ease of assembly. It is also available in a 4.0x4.0mm 8-Lead DFN package as a two channel device for high density requirements.

Typical Application Circuit



Ordering Information

Part Number	Package Options	Packing
MD0100DK6-G (Dual Channel)	8-Lead (4x4) DFN	3000/Reel
MD0100N8-G (Single Channel)	3-Lead TO-243AA (SOT-89)	2000/Reel

⁻G denotes a lead (Pb)-free / RoHS compliant package

Absolute Maximum Ratings¹

Parameter	Value
V _{A-B} , differential voltage drop	0 to ±110V
Maximum junction temperature	+125°C
Storage temperature range	-65°C to 150°C
Power dissipation, 8-Lead DFN ²	1.1W
Power dissipation, SOT-89 ²	1.6W

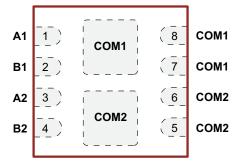
Notes:

- 1. Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.
- 2. Mounted on FR4 board, 25mm x 25mm x 1.57mm

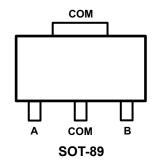
Typical Thermal Resistance

Package	$oldsymbol{ heta}_{ja}$
8-Lead DFN	44°C/W
3-Lead TO-243AA (SOT-89)	133°C/W

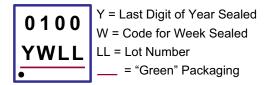
Pin Configuration



8-Lead DFN (top view) (Pads are at bottom of device)

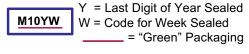


Product Marking



8-Lead DFN

Package may or may not include the following marks: Si or



SOT-89

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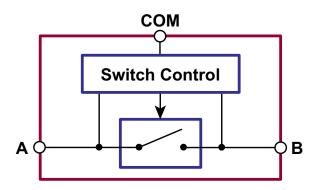
Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Sym	Parameter	Min	Тур	Max	Units	Conditions
V _{A-B}	Max. differential input voltage from A to B	±100	-	-	V	I _{A-B} = ±500μA
R _{sw}	Switch ON resistance from A to B	-	15	-	Ω	I _{A-B} = ±5.0mA
V _{TRIP}	V _{A-B} trip point to turn off	-	±1.0	±2.0	V	
V _{OFF}	Switch turn off voltage	-	±2.0	-	V	I _{A-B} = ±1.0mA
I _{A-B(OFF)}	Switch off current	-	±200	±300	μA	V _{A-B} = ±100V
I _{PEAK}	Peak switching current	-	±60	-	mA	See Fig. 8

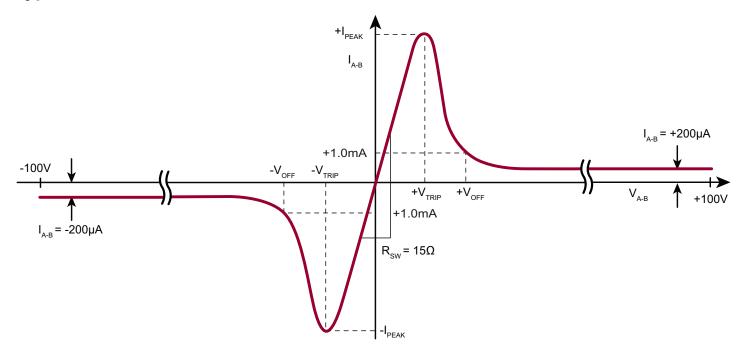
Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Sym	Parameter	Min	Тур	Max	Units	Conditions
T _{OFF}	Turn off time	ı	ı	20	ns	See Fig. 2, 3 & 4
T _{on}	Turn on time	-	-	20	ns	See Fig. 5, 6 & 7
C _{SW(ON)}	Switch ON capacitance from A to B	-	21	ı	pF	SW = ON
C _{SW(OFF)}	Switch OFF capacitance from A to B	-	15	-	pF	V _{SW} = 25V
BW	Small signal bandwidth	-	100	-	MHz	$R_{LOAD} = 50\Omega$
T_{J}	Operating junction temperature	-40	-	+125	°C	

Block Diagram



Typical I-V Characteristics



Functional Description

The Supertex MD0100 can be considered as a normally closed switch controlled by a switch control. (Refer to the block diagram.) The switch control monitors the voltage drop across terminals A and B. If the voltage difference is greater than ±2.0V, the T/R switch will start to open. Once in the open state, there is a small amount of current flowing through the T/R switch, 200uA, to detect if the high voltage is still present or not. The T/R switch will not close until the voltage across terminal A and B drops within ±2.0V. A pair of back-to-back diodes from the receive side of the switch to ground are needed to complete the circuit and to allow the initial peak current (about 60mA) to flow through the switch so it can drop ±2.0V. If the diodes are not present, then there is no current path and the voltage drop across terminal A and B will be less than ±2.0V, so the switch will remain in the closed position.

The other purpose of the diode is to clamp voltage spikes to ± 0.7 V during transmit cycle. A low voltage diode, for example 1.0V diode, is sufficient since it will only see ± 0.7 V. A BAV99T dual diode from Diodes, Inc. was used in our test circuit.

On Resistance

When the voltage across terminals A and B is within $\pm 2.0V$, the switch is in the receive mode, and the R_{ON} is typically 15 Ω . Once the voltage across terminals A and B is greater than $\pm 2.0V$, the switch is in the transmit mode and blocks the high voltage pulses from passing through to the receiver and damaging it.

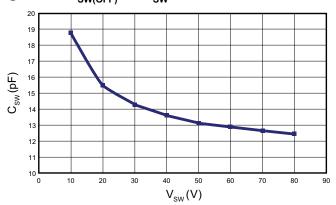
The MD0100 does not require any power supply. There are only two active pins; one connects to the transmitter side and the other one connects to the receiver side.

Switch Capacitance

The typical switch ON capacitance ($C_{\text{SW(ON)}}$) is 21pF. This is measured from A to B or B to A when the switch is ON.

The switch OFF capacitance is a function of the voltage across the T/R switch. The $C_{\rm SW(OFF)}$ is about 12 to 19 pF for 10V to 100V of the transmit voltage. Please see Figure 1 for the C-V curve of the $C_{\rm SW(OFF)}$.

Figure 1: $C_{SW(OFF)}$ vs V_{SW}



T_{ON} and T_{OFF} Time

The T_{ON} and T_{OFF} of the MD0100 are less than 20ns, which provide a fast switch between the transmit mode and the receive mode. The T_{ON} and T_{OFF} are input rise/fall time dependent. The MD0100 turns ON and OFF faster when the rise and fall times of the transmit pulse are faster. On the other hand, the switch turns ON and OFF slower if the rise and fall times of the transmit pulse are slower. The T_{OFF} and T_{ON} set up are shown in Figure 2 and Figure 5 respectively.

Figure 2: Test set up for Tope

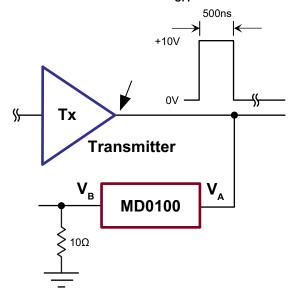


Figure 3: T_{OFF} Timing Diagram

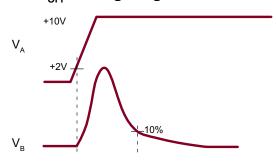


Figure 4: T_{OFF} at $V_A = 10V$

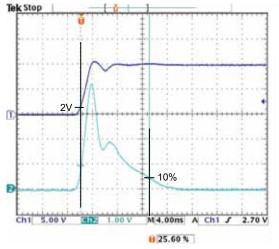


Figure 4 shows the actual waveform and measurement of the T_{OFF} . T_{OFF} is measured from 2V of the V_{A} to 10% of the V_{B} . From the above waveform, the T_{OFF} is 11ns.

Figure 5: Test Set Up for Ton

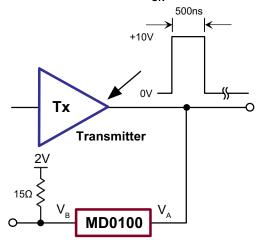


Figure 6: T_{on} Timing Diagram

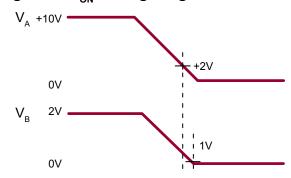


Figure 7: T_{ON} at $V_A = 10V$

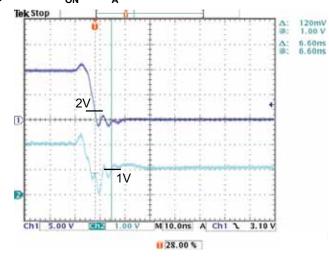


Figure 7 shows the actual waveform and measurement of the $T_{\rm ON}$. The $T_{\rm ON}$ is measured from 2V of the $V_{\rm A}$ to 1V of the $V_{\rm B}$. From the above waveform, the $T_{\rm ON}$ is 6.6ns.

Figure 8: Test Set Up for I_{PEAK}

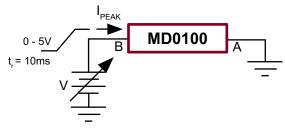


Figure 9: Typical Application Circuit

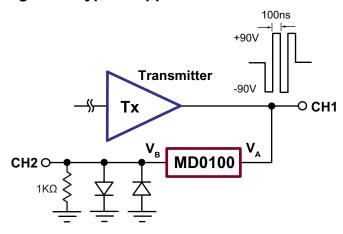


Figure 10: Typical Waveform

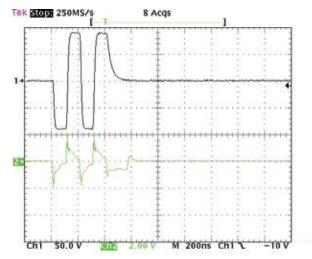


Figure 10 shows the waveforms of V_A and V_B of the test circuit shown in Figure 9. There is a small bump of about 0.5V at the tail of the V_B signal because the transmit signal falls into the $\pm 2.0 V$ range, and the MD0100 turns back ON again. Figure 11 shows a magnified view of the V_A .

Figure 11: Typical Waveform

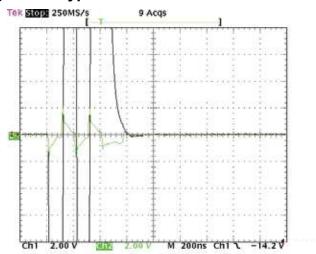


Figure 11 shows $\rm V_A$ and $\rm V_B$ in the same voltage scale, 2.0V/ DIV.

Pin Description (8-Lead DFN)

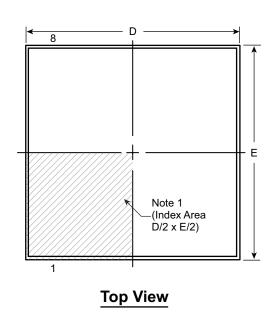
Pin	Name	Description
1	A1	Switch terminal A1
2	B1	Switch terminal B1
3	A2	Switch terminal A2
4	B2	Switch terminal B2
5	COM2	Leave fleeting
6	COM2	Leave floating
7	COM1	Leave fleeting
8	COM1	Leave floating
Heat Slug 1	COM1	Leave floating
Heat Slug 2	COM2	Leave floating

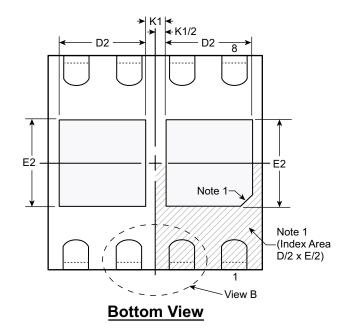
Pin Description (SOT-89)

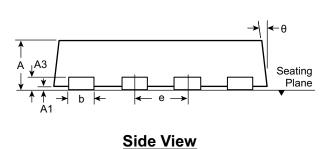
Name	Description
Α	Switch terminal A
СОМ	Leave floating
В	Switch terminal B

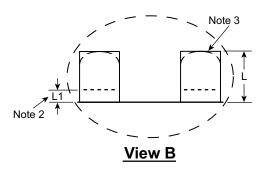
8-Lead DFN Package Outline (K6)

4.00x4.00mm body, 1.00mm height (max), 1.00mm pitch (dual pad)









Notes:

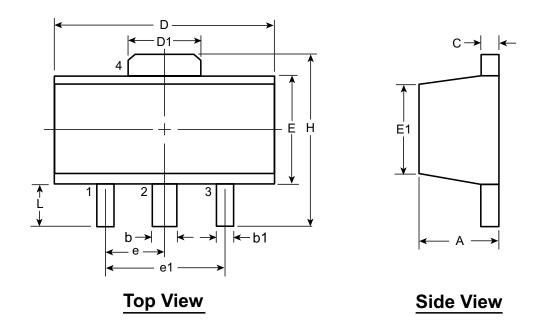
- A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.
- 2. Depending on the method of manufacturing, a maximum of 0.15mm pullback (L1) may be present.
- 3. The inner tip of the lead may be either rounded or square.

Symbo	ol	Α	A1	А3	b	D	D2	E	E2	е	K1	L	L1	θ
Dimension (mm)	MIN	0.80	0.00	0.20 REF	0.25	3.90	1.35	3.90	1.35	1.00 BSC	0.50 REF	0.40	0.00	0°
	NOM	0.90	-		0.30	4.00	1.45	4.00	1.45			0.50	-	-
	MAX	1.00	0.05		0.35	4.10	1.55	4.10	1.55			0.60	0.15	14º

Drawings not to scale

Supertex Doc. #: DSPD-8DFNK64x4P100, Version C010813

3-Lead TO-243AA (SOT-89) Package Outline (N8)



Symbo	ol	Α	b	b1	С	D	D1	Е	E1	е	e1	Н	L
Dimensions (mm)	MIN	1.40	0.44	0.36	0.35	4.40	1.62	2.29	2.00 [†]	1.50 3.00 BSC BSC		3.94	0.73 [†]
	NOM	-	-	-	-	-	-	-	-			-	-
	MAX	1.60	0.56	0.48	0.44	4.60	1.83	2.60	2.29			4.25	1.20

JEDEC Registration TO-243, Variation AA, Issue C, July 1986.

† This dimension differs from the JEDEC drawing

Drawings not to scale.

Supertex Doc. #: DSPD-3TO243AAN8, Version F111010.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

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